

### FEATURES

- ±50 mA Voltage Programmable Current Range
- Three Selectable Gain Ranges
- 1.5 ns Propagation Delay
- Inhibit Mode Function
- High Speed Differential Inputs for Maximum Flexibility
- Ultrasmall 20-Lead SOP Package with Built-In Heatsink

### APPLICATIONS

- Automatic Test Equipment
- Semiconductor Test Systems
- Board Test Systems

### PRODUCT DESCRIPTION

The AD53041 is a complete, high speed, current switching load designed for use in linear, digital or mixed signal test systems. Combining a high speed monolithic process with a unique surface mount package, this product attains superb electrical performance while preserving optimum packaging densities in an ultrasmall 20-lead, SOP package with a built-in heatsink.

Featuring current programmability of up to ±50 mA, the AD53041 is designed to force the device under test to source or sink the programmed  $I_{OH}$  and  $I_{OL}$  currents.  $I_{OH}$  and  $I_{OL}$  currents are determined by applying a corresponding voltage (5 V = 50 mA, 16 mA, 5 mA) to the  $I_{OH}$  and  $I_{OL}$  pins. The voltage-to-current conversion is performed within the AD53041, thus allowing the current levels to be set by a standard voltage out digital-to-analog converter.

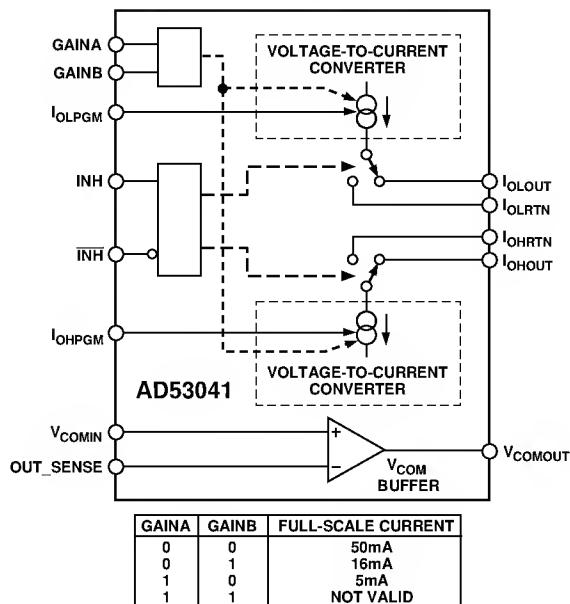
The AD53041 transition from  $I_{OH}$  to  $I_{OL}$  occurs when the output voltage of the device under test slews above or below the programmed threshold or commutation voltage. The commutation voltage is programmable from -2 V to +7 V, covering the large spectrum of logic devices while able to support the large current specifications (48 mA) typically associated with line drivers. To test I/O devices, the active load can be switched into a high impedance state (Inhibit Mode), electrically removing the active load from the path through the Inhibit Mode feature. The active load leakage current in Inhibit is typically 100 nA.

The Inhibit input circuitry is implemented using high speed differential inputs with a common-mode voltage range of -2 V to +3 V and a maximum differential voltage of 3 V. This allows for direct interface to precision differential ECL timing or the simplicity of switching active load from a single ended TTL or CMOS logic source. With switching speeds from  $I_{OH}$  or  $I_{OL}$  into Inhibit of less than 2.0 ns, the AD53041 can be electrically removed from the signal path "on the fly."

REV. 0

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### FUNCTIONAL BLOCK DIAGRAM



The AD53041 is available in a 20-lead, SOP package with a built-in-heatsink and is specified to operate over the ambient commercial temperature range from -25°C to +85°C.

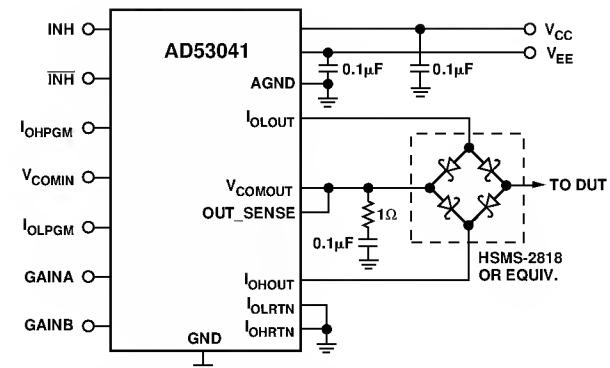


Figure 1. Typical Application Circuit

# AD53041—SPECIFICATIONS

(All specifications apply at  $T_J = 85^\circ\text{C} \pm 5^\circ\text{C}$ .  $+V_S = +10.5\text{ V} \pm 3\%$ ,  $-V_S = -5.2\text{ V} \pm 3\%$

unless otherwise specified.  $V_{COMOUT}$  is bypassed to ground with a series RC consisting of a  $1\ \Omega$  resistor and a  $0.1\ \mu\text{F}$  capacitor, and is also connected directly to OUT\_SENSE. All temperature coefficients are characterized over  $T_J = 75^\circ\text{C}$ – $95^\circ\text{C}$ .)

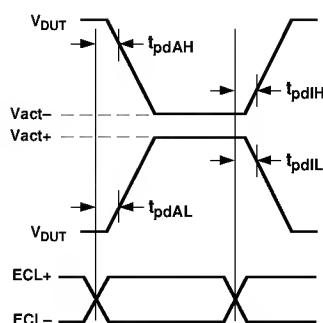
Parameter	Min	Typ	Max	Units	Test Conditions
INPUT CHARACTERISTICS INH, $\overline{\text{INH}}$					
Input Voltage	-2	ECL	3	V	
Bias Current	-1		1	mA	$\text{INH}, \overline{\text{INH}} = -2\text{ V}, 0\text{ V}$
GAINA, GAINB					
Input Voltage	0	TTL/CMOS	5	V	
Bias Current	0		2	mA	$\text{GAINA}, \text{GAINB} = 5\text{ V}$
$I_{OHPGM}, I_{OLPGM}$ Voltage Range					
$I_{OH}$ , 0 to + Full Scale, Any Gain Range	-0.1		5.2	V	$V(I_{OHOUT}) = -2\text{ V}, 7\text{ V}$
$I_{OL}$ , 0 to – Full Scale, Any Gain Range	-0.1		5.2	V	$V(I_{OLOUT}) = -2\text{ V}, 7\text{ V}$
$I_{OHPGM}, I_{OLPGM}$ Bias Current	-300		300	$\mu\text{A}$	$V(I_{OHPGM}) = +5\text{ V}, V(I_{OLPGM}) = 0\text{ V}$
$V_{COM}$ BUFFER					
Voltage Range	-2		7	V	$\pm 50\text{ mA}$ Output Current
Offset		$\pm 5$		mV	$V_{COM} = 0\text{ V}$
Offset Drift		0.1		$\text{mV}/^\circ\text{C}$	$V_{COM} = 0\text{ V}$
Nonlinearity		$\pm 2$		mV	$V_{COM} = -2\text{ V}$ to $7\text{ V}$
Input Bias Current	-50		50	$\mu\text{A}$	$V_{COM} = -2\text{ V}$ to $7\text{ V}$
Output Resistance		<1		$\Omega$	$V_{COM} = 0\text{ V}, I_{OUT} = \pm 50\text{ mA}$
OUTPUT CHARACTERISTICS					
Full-Scale Current Range					See Functional Block Diagram
Range 0		50		mA	
Range 1		16		mA	
Range 2		5		mA	
Offset Error					
Range 0	-1		1	mA	$V(I_{OHPGM}) = V(I_{OLPGM}) = 100\text{ mV}$ ,
Range 1	-0.3		0.3	mA	$V(I_{OHOUT}) = \pm 2\text{ V}, V(I_{OLOUT}) = \pm 2\text{ V}$
Range 2	-0.3		0.3	mA	
Offset Drift					
Range 0		1		$\mu\text{A}/^\circ\text{C}$	$V(I_{OHPGM}) = V(I_{OLPGM}) = 100\text{ mV}$ ,
Range 1		1		$\mu\text{A}/^\circ\text{C}$	$V(I_{OHOUT}) = V(I_{OLOUT}) = 0\text{ V}$
Range 2		1		$\mu\text{A}/^\circ\text{C}$	
Gain Error					
Range 0		<1		% FSR	
Range 1		<5		% FSR	
Range 2		<8		% FSR	
Gain Drift					
Range 0		1		$\mu\text{A}/^\circ\text{C}$	
Range 1		0.5		$\mu\text{A}/^\circ\text{C}$	
Range 2		0.3		$\mu\text{A}/^\circ\text{C}$	
Gain Ratio Drift					
Range 1 to Range 0		0.01		$^\circ\text{C}$	
Range 2 to Range 0		0.01		$^\circ\text{C}$	
Nonlinearity		$\pm 0.05$		% FSR	Range 0
Common-Mode Error		$\pm 0.05$		%FSR	Range 0
PSRR		$\pm 0.1$		%FSR/V	Range 0, $V(I_{OHPGM}) = V(I_{OLPGM}) = 100\text{ mV}$ , Either Supply Over Operating Range
OUTPUT VOLTAGE RANGE					
$I_{OHOUT}, I_{OHRDN}$	-2.5		7.5	V	$I_{OH} = 50\text{ mA}$
$I_{OLOUT}, I_{OLRTN}$	-2.5		7.5	V	$I_{OL} = 50\text{ mA}$

Parameter	Min	Typ	Max	Units	Test Conditions
LEAKAGE CURRENTS					Range 0, Bridge Diode Leakage Not Included
I <sub>OH</sub> Inhibit-Mode Leakage	-1	1	1	μA	V(I <sub>OHPGM</sub> ) = -2.5 V to 7.5 V, Inhibited
I <sub>OL</sub> Inhibit-Mode Leakage	-1	1	1	μA	V(I <sub>OLPGM</sub> ) = -2.5 V to 7.5 V, Inhibited
I <sub>OH</sub> Off-State Leakage	-3	3	3	μA	V(I <sub>OHPGM</sub> ) = -0.2 V
I <sub>OL</sub> Off-State Leakage	-3	3	3	μA	V(I <sub>OLPGM</sub> ) = -2.5 V to 7.5 V, V(I <sub>OHPGM</sub> ) = -0.2 V
DYNAMIC PERFORMANCE					
Propagation Delays					
±I <sub>MAX</sub> to Inhibit		1.8		ns	Range 0, I <sub>MAX</sub> , R <sub>LOAD</sub> = 50 Ω
Part-to-Part Skew		1		ns	
Inhibit to ±I <sub>MAX</sub>		1.3		ns	Range 0, I <sub>MAX</sub> , R <sub>LOAD</sub> = 50 Ω
Part-to-Part Skew		1		ns	
Propagation Delay Drift		10		ps/°C	±I <sub>MAX</sub> to Inhibit, Inhibit to ±I <sub>MAX</sub>
Capacitance		3		pF	I <sub>OHPGM</sub> or I <sub>OLPGM</sub> Without Diodes
POWER SUPPLIES					
-V <sub>S</sub> to +V <sub>S</sub> Range	15.2	15.7	16.2	V	
Positive Supply Range	10.2	10.5	10.8	V	
Negative Supply Range	-5.4	-5.2	-5.0	V	
Positive Supply Current			160	mA	Range 0, V(I <sub>OHPGM</sub> ) = 5.0 V, Active
	35		60	mA	Range 0, V(I <sub>OLPGM</sub> ) = 200 mV, Active
Negative Supply Current			160	mA	Range 0, V(I <sub>OHPGM</sub> ) = 5.0 V, Active
	35		60	mA	Range 0, V(I <sub>OLPGM</sub> ) = 200 mV, Active
Power Dissipation		2.1	2.3	W	I <sub>OH</sub> = 50 mA, I <sub>OL</sub> = -50 mA, Active, V(I <sub>OHPGM</sub> ) = 7 V, V(I <sub>OLPGM</sub> ) = -2 V

Specifications subject to change without notice.

Table I. Active Load Truth Table  
(Including External Diode Bridge Per Figure 1; Scale Factors Per Functional Block Diagram)

V(DUT)	INH	INH	OUTPUT STATES (IFS Is Full-Scale Current Set by GAINA, GAINB)		
			I <sub>OH</sub>	I <sub>OL</sub>	I(V <sub>DUT</sub> )
< V <sub>COM</sub>	0	1	[V(I <sub>OHPGM</sub> ) ÷ 5 V] × IFS	[V(I <sub>OLPGM</sub> ) ÷ 5 V] × IFS	I <sub>OL</sub>
> V <sub>COM</sub>	0	1	[V(I <sub>OHPGM</sub> ) ÷ 5 V] × IFS	[V(I <sub>OLPGM</sub> ) ÷ 5 V] × IFS	I <sub>OH</sub>
X	1	0	0	0	0



PROPAGATION DELAY LOAD AND TEST CONDITIONS					
PARAMETER	DESCRIPTION	I <sub>OL</sub>	I <sub>OH</sub>	V <sub>DUT</sub>	MEASURE POINT
t <sub>pdAH</sub>	I <sub>OL</sub> Inh → Act	50mA	50mA	0V	0.50V
t <sub>pdlL</sub>	I <sub>OL</sub> Act → Inh	50mA	50mA	0V	2.00V
t <sub>pdAH</sub>	I <sub>OH</sub> Inh → Act	50mA	50mA	5V	4.50V
t <sub>pdlH</sub>	I <sub>OH</sub> Act → Inh	50mA	50mA	5V	3.00V

Figure 2. Inhibit Propagation Delay Measurement

